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### Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	684
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	104
Number of Gates	4000
Voltage - Supply	4.5V ~ 5.5V
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 125°C (TC)
Package / Case	144-BQFP
Supplier Device Package	144-PQFP (28x28)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microsemi/a1240a-1pqg144m">https://www.e-xfl.com/product-detail/microsemi/a1240a-1pqg144m</a>

## Ordering Information



To calculate the active power dissipated from the complete design, the switching frequency of each part of the logic must be known. EQ 4 shows a piece-wise linear summation over all components.

$$\begin{aligned}
 \text{Power} = & VCC^2 * [(m * C_{EQM} * f_m)_{\text{modules}} + (n * C_{EQI} * f_n)_{\text{inputs}} \\
 & + (p * (C_{EQO} + C_L) * f_p)_{\text{outputs}} \\
 & + 0.5 * (q1 * C_{EQCR} * f_{q1})_{\text{routed\_Clk1}} + (r1 * f_{q1})_{\text{routed\_Clk1}} \\
 & + 0.5 * (q2 * C_{EQCR} * f_{q2})_{\text{routed\_Clk2}} + (r2 * f_{q2})_{\text{routed\_Clk2}}
 \end{aligned}$$

EQ 4

Where:

m = Number of logic modules switching at  $f_m$

n = Number of input buffers switching at  $f_n$

p = Number of output buffers switching at  $f_p$

q1 = Number of clock loads on the first routed array clock

q2 = Number of clock loads on the second routed array clock

$r_1$  = Fixed capacitance due to first routed array clock

$r_2$  = Fixed capacitance due to second routed array clock

$C_{EQM}$  = Equivalent capacitance of logic modules in pF

$C_{EQI}$  = Equivalent capacitance of input buffers in pF

$C_{EQO}$  = Equivalent capacitance of output buffers in pF

$C_{EQCR}$  = Equivalent capacitance of routed array clock in pF

$C_L$  = Output lead capacitance in pF

$f_m$  = Average logic module switching rate in MHz

$f_n$  = Average input buffer switching rate in MHz

$f_p$  = Average output buffer switching rate in MHz

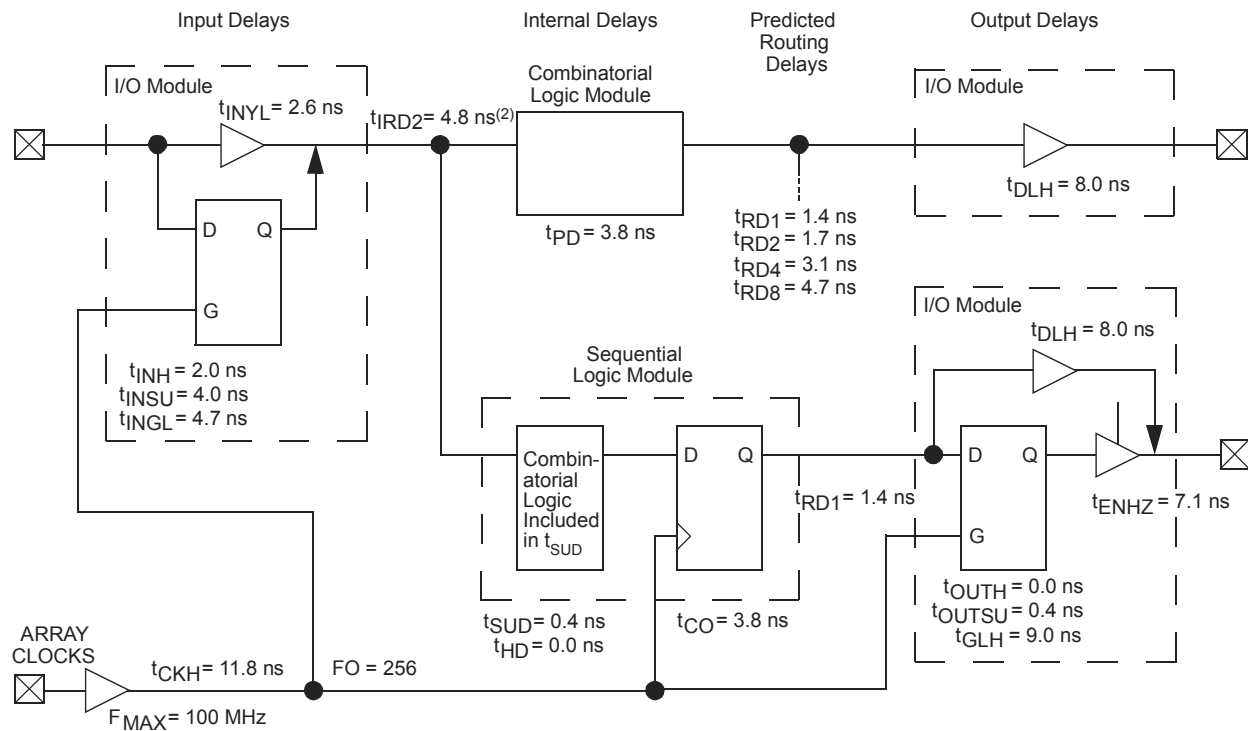
$f_{q1}$  = Average first routed array clock rate in MHz

$f_{q2}$  = Average second routed array clock rate in MHz

**Table 2-7 • Fixed Capacitance Values for Microsemi FPGAs**

Device Type	$r_1$ , routed_Clk1	$r_2$ , routed_Clk2
A1225A	106	106.0
A1240A	134	134.2
A1280A	168	167.8

## ACT 2 Timing Model<sup>1</sup>

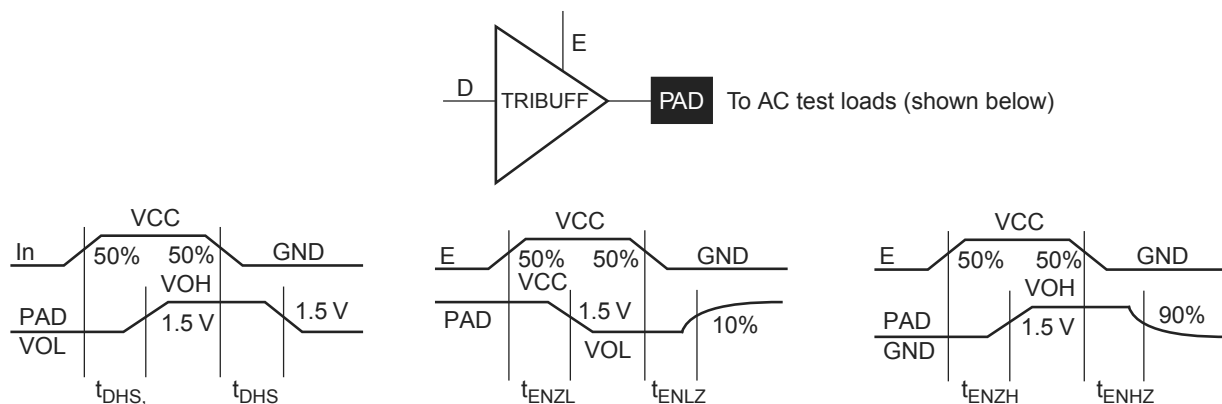


Notes:

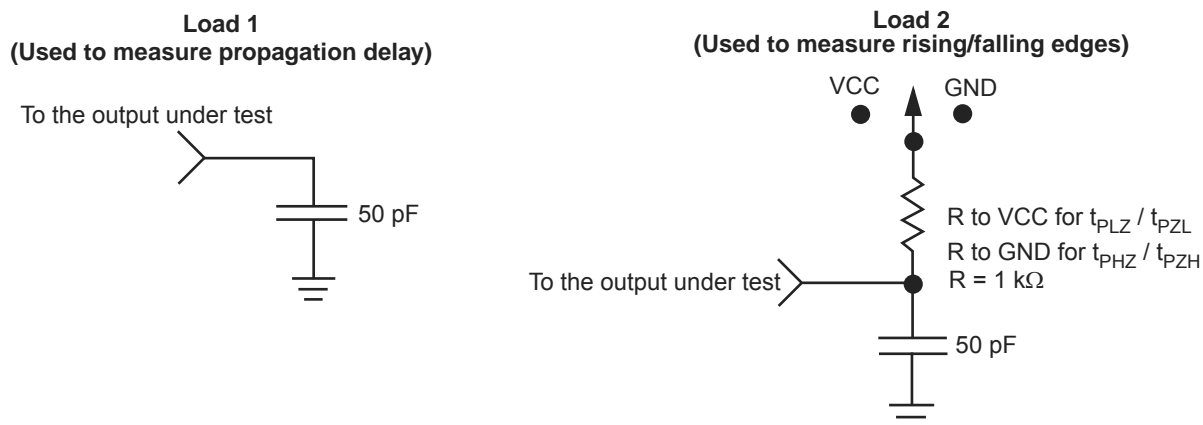
1. Values shown for A1240A-2 at worst-case commercial conditions.
2. Input module predicted routing delay

**Figure 2-1 • Timing Model**

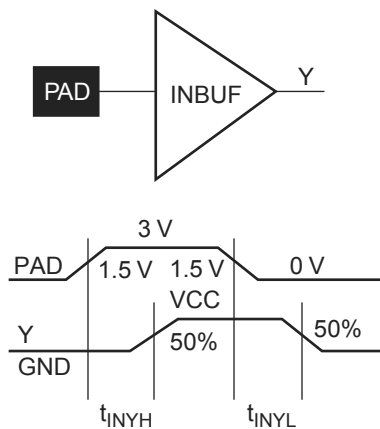
## Parameter Measurement



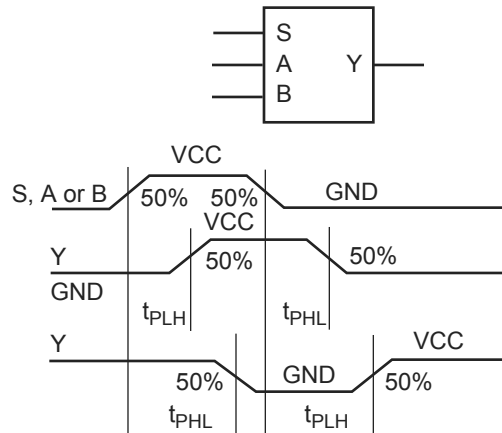
**Figure 2-2 • Output Buffer Delays**



**Figure 2-3 • AC Test Loads**

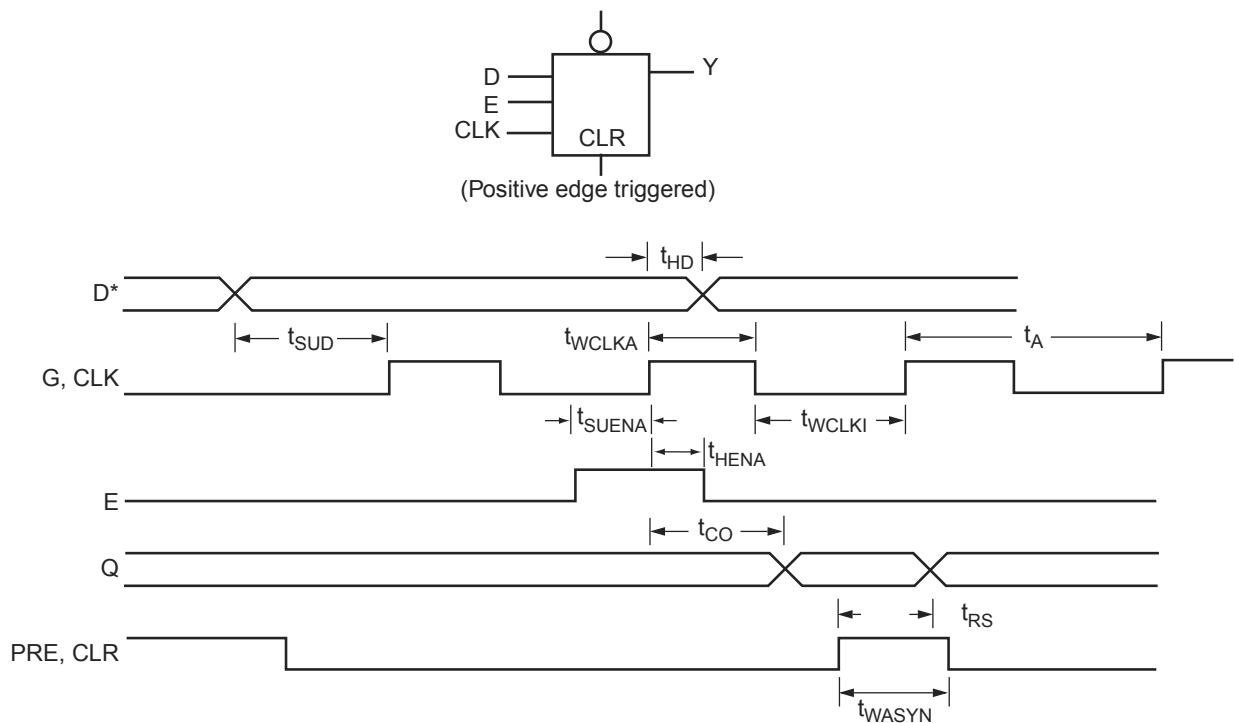


**Figure 2-4 • Input Buffer Delays**



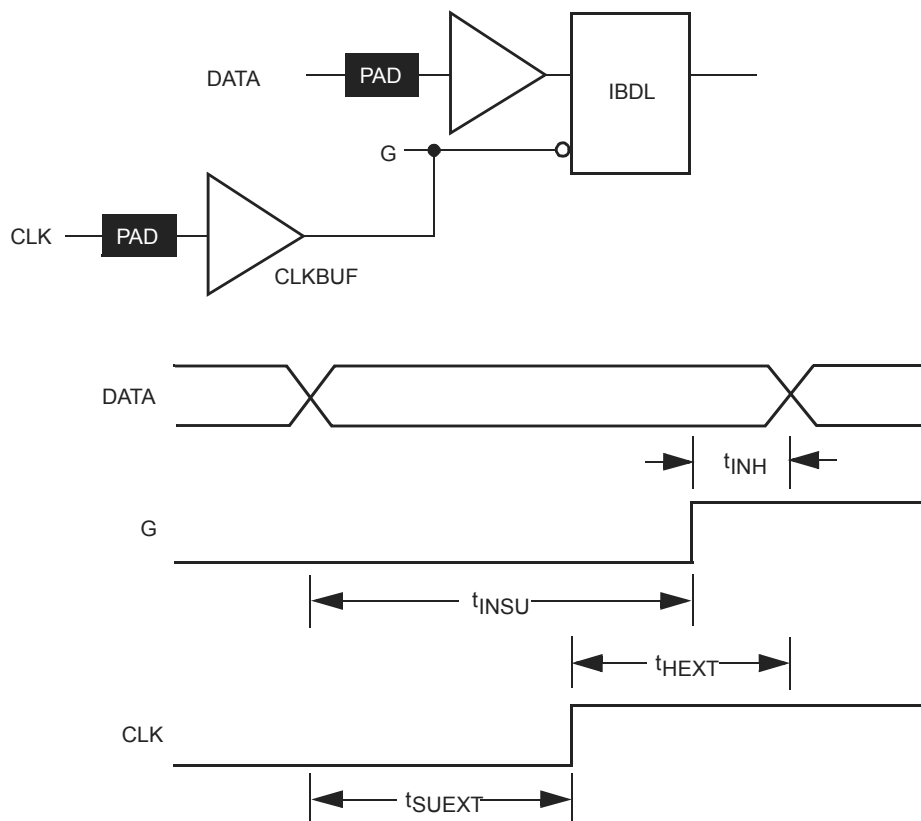
**Figure 2-5 • Module Delays**

## Sequential Module Timing Characteristics

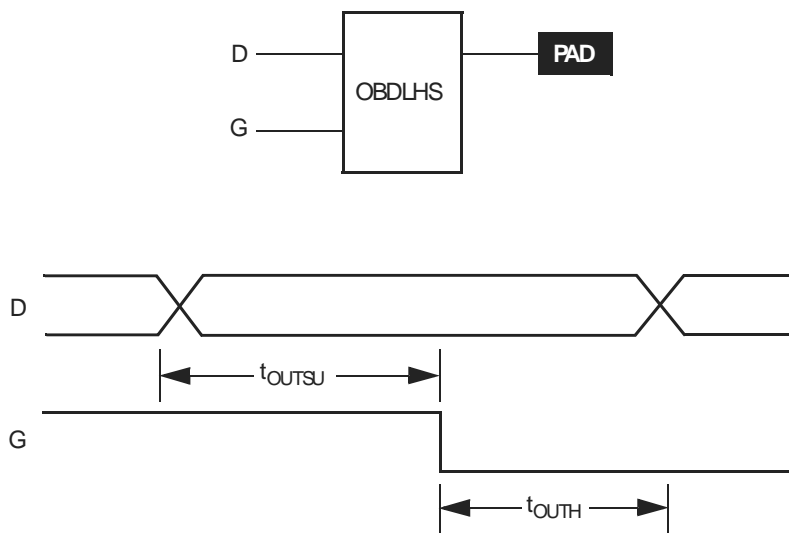


*Note: D represents all data functions involving A, B, and S for multiplexed flip-flops.*

**Figure 2-6 • Flip-Flops and Latches**



**Figure 2-7 • Input Buffer Latches**



**Figure 2-8 • Output Buffer Latches**

## Timing Derating Factor (Temperature and Voltage)

**Table 2-9 • Timing Derating Factor (Temperature and Voltage)**

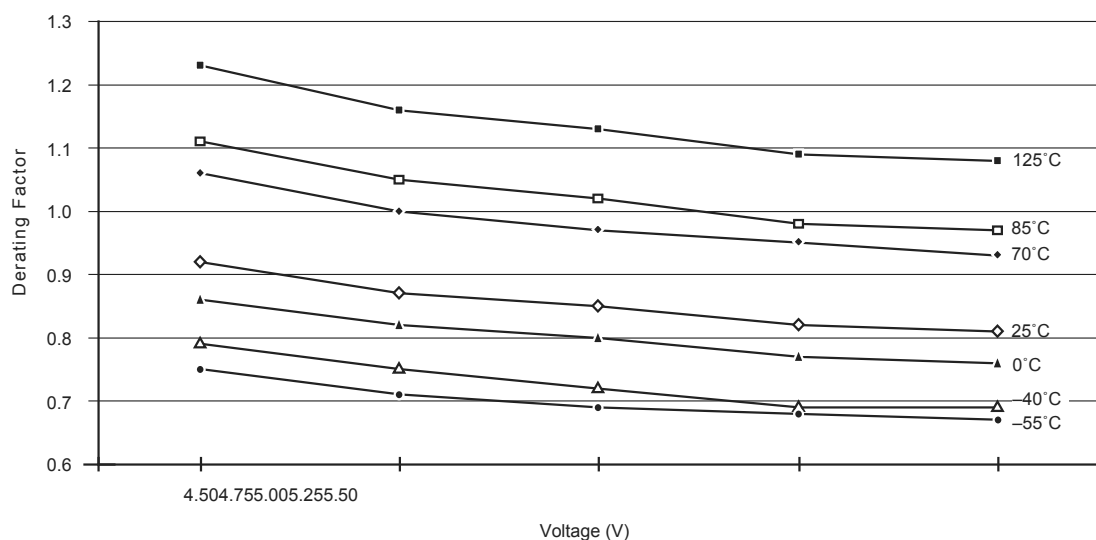
(Commercial Minimum/Maximum Specification) x	Industrial		Military	
	Min.	Max.	Min.	Max.
	0.69	1.11	0.67	1.23

**Table 2-10 • Timing Derating Factor for Designs at Typical Temperature ( $T_J = 25^\circ\text{C}$ ) and Voltage (5.0 V)**

(Commercial Maximum Specification) x	0.85
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**Table 2-11 • Temperature and Voltage Derating Factors  
(normalized to Worst-Case Commercial,  $T_J = 4.75\text{ V}$ ,  $70^\circ\text{C}$ )**

	-55	-40	0	25	70	85	125
<b>4.50</b>	0.75	0.79	0.86	0.92	1.06	1.11	1.23
<b>4.75</b>	0.71	0.75	0.82	0.87	1.00	1.05	1.13
<b>5.00</b>	0.69	0.72	0.80	0.85	0.97	1.02	1.13
<b>5.25</b>	0.68	0.69	0.77	0.82	0.95	0.98	1.09
<b>5.50</b>	0.67	0.69	0.76	0.81	0.93	0.97	1.08



*Note: This derating factor applies to all routing and propagation delays.*

**Figure 2-9 • Junction Temperature and Voltage Derating Curves  
(normalized to Worst-Case Commercial,  $T_J = 4.75\text{ V}$ ,  $70^\circ\text{C}$ )**



## A1280A Timing Characteristics

**Table 2-18 • A1280A Worst-Case Commercial Conditions, VCC = 4.75 V, T<sub>J</sub> = 70°C**

Logic Module Propagation Delays <sup>1</sup>		–2 Speed <sup>3</sup>		–1 Speed		Std. Speed		Units
Parameter/Description		Min.	Max.	Min.	Max.	Min.	Max.	
t <sub>PD1</sub>	Single Module		3.8		4.3		5.0	ns
t <sub>CO</sub>	Sequential Clock to Q		3.8		4.3		5.0	ns
t <sub>GO</sub>	Latch G to Q		3.8		4.3		5.0	ns
t <sub>RS</sub>	Flip-Flop (Latch) Reset to Q		3.8		4.3		5.0	ns
<b>Predicted Routing Delays<sup>2</sup></b>								
t <sub>RD1</sub>	FO = 1 Routing Delay		1.7		2.0		2.3	ns
t <sub>RD2</sub>	FO = 2 Routing Delay		2.5		2.8		3.3	ns
t <sub>RD3</sub>	FO = 3 Routing Delay		3.0		3.4		4.0	ns
t <sub>RD4</sub>	FO = 4 Routing Delay		3.7		4.2		4.9	ns
t <sub>RD8</sub>	FO = 8 Routing Delay		6.7		7.5		8.8	ns
<b>Sequential Timing Characteristics<sup>3,4</sup></b>								
t <sub>SUD</sub>	Flip-Flop (Latch) Data Input Setup	0.4		0.4		0.5		ns
t <sub>HD</sub>	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		ns
t <sub>SUENA</sub>	Flip-Flop (Latch) Enable Setup	0.8		0.9		1.0		ns
t <sub>HENA</sub>	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		ns
t <sub>WCLKA</sub>	Flip-Flop (Latch) Clock Active Pulse Width	5.5		6.0		7.0		ns
t <sub>WASYN</sub>	Flip-Flop (Latch) Clock Asynchronous Pulse Width	5.5		6.0		7.0		ns
t <sub>A</sub>	Flip-Flop Clock Input Period	11.7		13.3		18.0		ns
t <sub>INH</sub>	Input Buffer Latch Hold	0.0		0.0		0.0		ns
t <sub>INSU</sub>	Input Buffer Latch Setup	0.4		0.4		0.5		ns
t <sub>OUTH</sub>	Output Buffer Latch Hold	0.0		0.0		0.0		ns
t <sub>OUTSU</sub>	Output Buffer Latch Setup	0.4		0.4		0.5		ns
f <sub>MAX</sub>	Flip-Flop (Latch) Clock Frequency		85.0		75.0		50.0	MHz

**Notes:**

1. For dual-module macros, use t<sub>PD1</sub> + t<sub>RD1</sub> + t<sub>PDn</sub>, t<sub>CO</sub> + t<sub>RD1</sub> + t<sub>PDn</sub>, or t<sub>PD1</sub> + t<sub>RD1</sub> + t<sub>SUD</sub>—whichever is appropriate.
2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.
3. Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the DirectTime Analyzer utility.
4. Setup and hold timing parameters for the Input Buffer Latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.

## A1280A Timing Characteristics (continued)

Table 2-19 • A1280A Worst-Case Commercial Conditions, VCC = 4.75 V, T<sub>J</sub> = 70°C

I/O Module Input Propagation Delays			–2 Speed		–1 Speed		Std. Speed		Units
Parameter/Description			Min.	Max.	Min.	Max.	Min.	Max.	
t <sub>INYH</sub>	Pad to Y High			2.9		3.3		3.8	ns
t <sub>INYL</sub>	Pad to Y Low			2.7		3.0		3.5	ns
t <sub>INGH</sub>	G to Y High			5.0		5.7		6.6	ns
t <sub>INGL</sub>	G to Y Low			4.8		5.4		6.3	ns
<b>Input Module Predicted Input Routing Delays*</b>									
t <sub>IRD1</sub>	FO = 1 Routing Delay			4.6		5.1		6.0	ns
t <sub>IRD2</sub>	FO = 2 Routing Delay			5.2		5.9		6.9	ns
t <sub>IRD3</sub>	FO = 3 Routing Delay			5.6		6.3		7.4	ns
t <sub>IRD4</sub>	FO = 4 Routing Delay			6.5		7.3		8.6	ns
t <sub>IRD8</sub>	FO = 8 Routing Delay			9.4		10.5		12.4	ns
<b>Global Clock Network</b>									
t <sub>CKH</sub>	Input Low to High	FO = 32		10.2		11.0		12.8	ns
		FO = 256		13.1		14.6		17.2	
t <sub>CKL</sub>	Input High to Low	FO = 32		10.2		11.0		12.8	ns
		FO = 256		13.3		14.9		17.5	
t <sub>PWH</sub>	Minimum Pulse Width High	FO = 32	5.0		5.5		6.6		ns
		FO = 256	5.8		6.4		7.6		
t <sub>PWL</sub>	Minimum Pulse Width Low	FO = 32	5.0		5.5		6.6		ns
		FO = 256	5.8		6.4		7.6		
t <sub>CKSW</sub>	Maximum Skew	FO = 32		0.5		0.5		0.5	ns
		FO = 256		2.5		2.5		2.5	
t <sub>SUEXT</sub>	Input Latch External Setup	FO = 32	0.0		0.0		0.0		ns
		FO = 256	0.0		0.0		0.0		
t <sub>HEXT</sub>	Input Latch External Hold	FO = 32	7.0		7.0		7.0		ns
		FO = 256	11.2		11.2		11.2		
t <sub>P</sub>	Minimum Period	FO = 32	9.6		11.2		13.3		ns
		FO = 256	10.6		12.6		15.3		
f <sub>MAX</sub>	Maximum Frequency	FO = 32		105.0		90.0		75.0	ns
		FO = 256		95.0		80.0		65.0	

Note: \*These parameters should be used for estimating device performance. Optimization techniques may further reduce delays by 0 to 4 ns. Routing delays are for typical designs across worst-case operating conditions. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

## A1280A Timing Characteristics (continued)

## Pin Descriptions

**CLKA                      Clock A (Input)**

TTL Clock input for clock distribution networks. The Clock input is buffered prior to clocking the logic modules. This pin can also be used as an I/O.

**CLKB                      Clock B (Input)**

TTL Clock input for clock distribution networks. The Clock input is buffered prior to clocking the logic modules. This pin can also be used as an I/O.

**DCLK                      Diagnostic Clock (Input)**

TTL Clock input for diagnostic probe and device programming. DCLK is active when the MODE pin is High. This pin functions as an I/O when the MODE pin is Low.

**GND                      Ground**

Low supply voltage.

**I/O                      Input/Output (Input, Output)**

The I/O pin functions as an input, output, three-state, or bidirectional buffer. Input and output levels are compatible with standard TTL and CMOS specifications. Unused I/O pins are automatically driven Low by the ALS software.

**MODE                      Mode (Input)**

The MODE pin controls the use of multifunction pins (DCLK, PRA, PRB, SDI). When the MODE pin is High, the special functions are active. When the MODE pin is Low, the pins function as I/Os. To provide Actionprobe capability, the MODE pin should be terminated to GND through a 10K resistor so that the MODE pin can be pulled High when required.

**NC                      No Connection**

This pin is not connected to circuitry within the device.

**PRA                      Probe A (Output)**

The Probe A pin is used to output data from any user-defined design node within the device. This independent diagnostic pin can be used in conjunction with the Probe B pin to allow real-time diagnostic output of any signal path within the device. The Probe A pin can be used as a user-defined I/O when debugging has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality. PRA is active when the MODE pin is High. This pin functions as an I/O when the MODE pin is Low.

**PRB                      Probe B (Output)**

The Probe B pin is used to output data from any user-defined design node within the device. This independent diagnostic pin can be used in conjunction with the Probe A pin to allow real-time diagnostic output of any signal path within the device. The Probe B pin can be used as a user-defined I/O when debugging has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality. PRB is active when the MODE pin is High. This pin functions as an I/O when the MODE pin is Low.

**SDI                      Serial Data Input (Input)**

Serial data input for diagnostic probe and device programming. SDI is active when the MODE pin is High. This pin functions as an I/O when the MODE pin is Low.

**SDO                      Serial Data Output (Output)**

Serial data output for diagnostic probe. SDO is active when the MODE pin is High. This pin functions as an I/O when the MODE pin is Low.

**VCC                      5.0 V Supply Voltage**

High supply voltage.

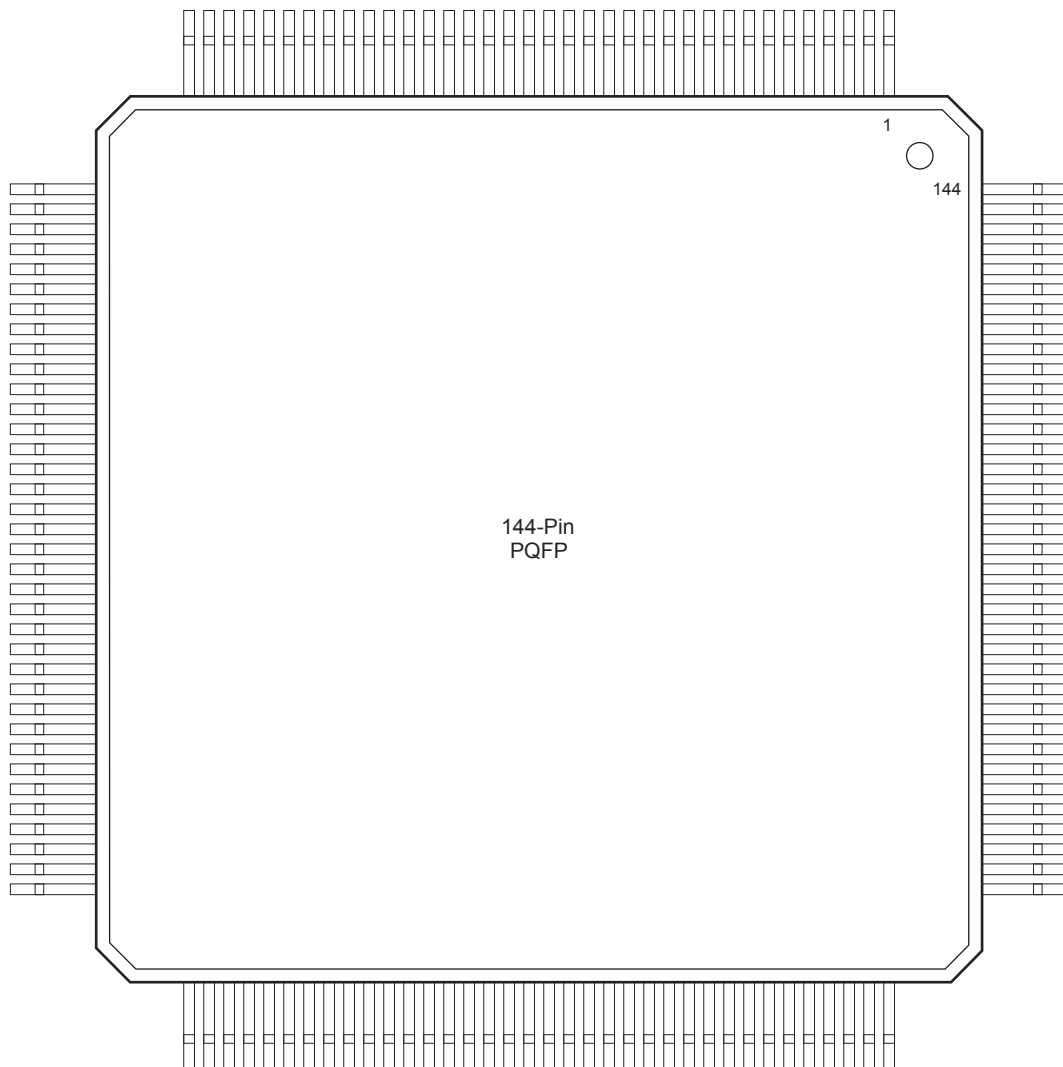
PL84			
Pin Number	A1225A Function	A1240A Function	A1280A Function
2	CLKB, I/O	CLKB, I/O	CLKB, I/O
4	PRB, I/O	PRB, I/O	PRB, I/O
6	GND	GND	GND
10	DCLK, I/O	DCLK, I/O	DCLK, I/O
12	MODE	MODE	MODE
22	VCC	VCC	VCC
23	VCC	VCC	VCC
28	GND	GND	GND
43	VCC	VCC	VCC
49	GND	GND	GND
52	SDO	SDO	SDO
63	GND	GND	GND
64	VCC	VCC	VCC
65	VCC	VCC	VCC
70	GND	GND	GND
76	SDI, I/O	SDI, I/O	SDI, I/O
81	PRA, I/O	PRA, I/O	PRA, I/O
83	CLKA, I/O	CLKA, I/O	CLKA, I/O
84	VCC	VCC	VCC

*Notes:*

1. All unlisted pin numbers are user I/Os.
2. MODE pin should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

## PQ144

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### **Note**

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>

PQ144	
Pin Number	A1240A Function
2	MODE
9	GND
10	GND
11	GND
18	VCC
19	VCC
20	VCC
21	VCC
28	GND
29	GND
30	GND
44	GND
45	GND
46	GND
54	VCC
55	VCC
56	VCC
64	GND
65	GND
71	SDO
79	GND
80	GND
81	GND
88	GND

PQ144	
Pin Number	A1240A Function
89	VCC
90	VCC
91	VCC
92	VCC
93	VCC
100	GND
101	GND
102	GND
110	SDI, I/O
116	GND
117	GND
118	GND
123	PRA, I/O
125	CLKA, I/O
126	VCC
127	VCC
128	VCC
130	CLKB, I/O
132	PRB, I/O
136	GND
137	GND
138	GND
144	DCLK, I/O

*Notes:*

1. All unlisted pin numbers are user I/Os.
2. MODE pin should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

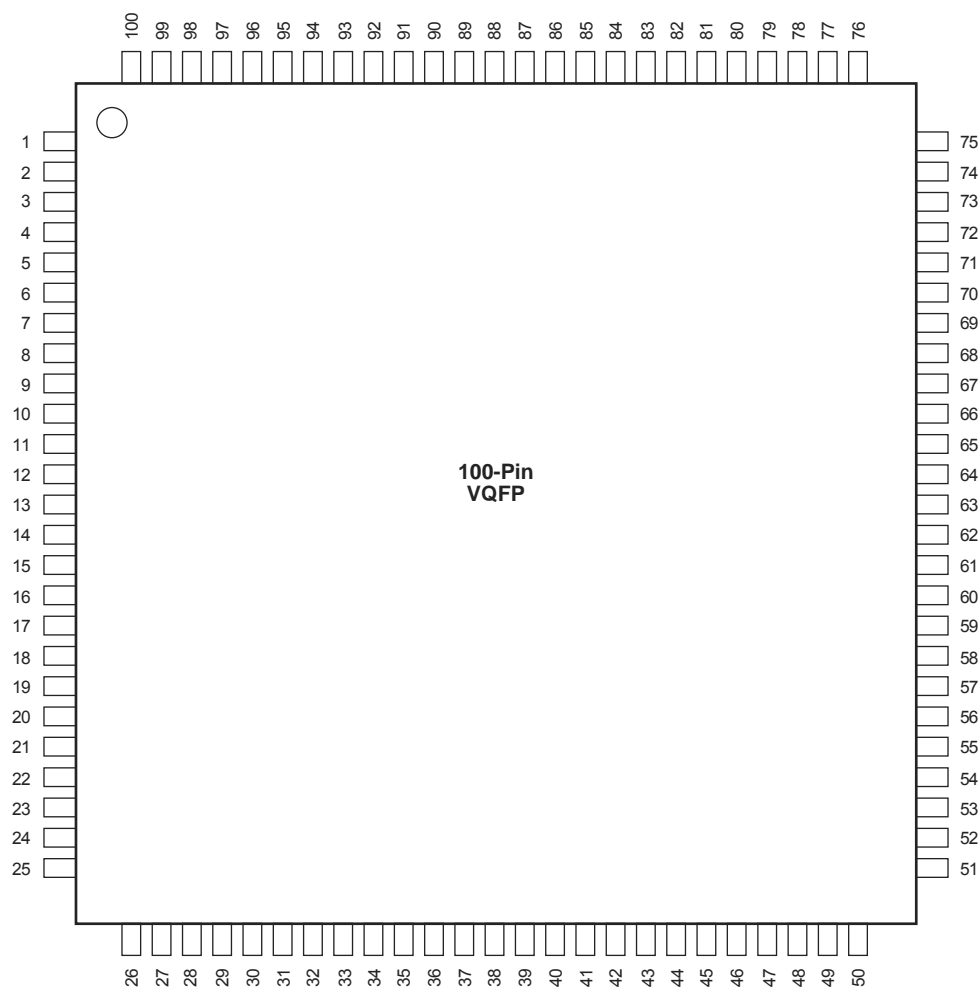
PQ160	
Pin Number	A1280A Function
2	DCLK, I/O
6	VCC
11	GND
16	PRB, I/O
18	CLKB, I/O
20	VCC
21	CLKA, I/O
23	PRA, I/O
30	GND
35	VCC
38	SDI, I/O
40	GND
44	GND
49	GND
54	VCC
57	VCC
58	VCC
59	GND
60	VCC
61	GND
64	GND

PQ160	
Pin Number	A1280A Function
69	GND
80	GND
82	SDO
86	VCC
89	GN
98	GND
99	GND
109	GND
114	VCC
120	GND
125	GND
130	GND
135	VCC
138	VCC
139	VCC
140	GND
145	GND
150	VCC
155	GND
159	MODE
160	GND

*Notes:*

1. All unlisted pin numbers are user I/Os.
2. MODE pin should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

## VQ100



### Note

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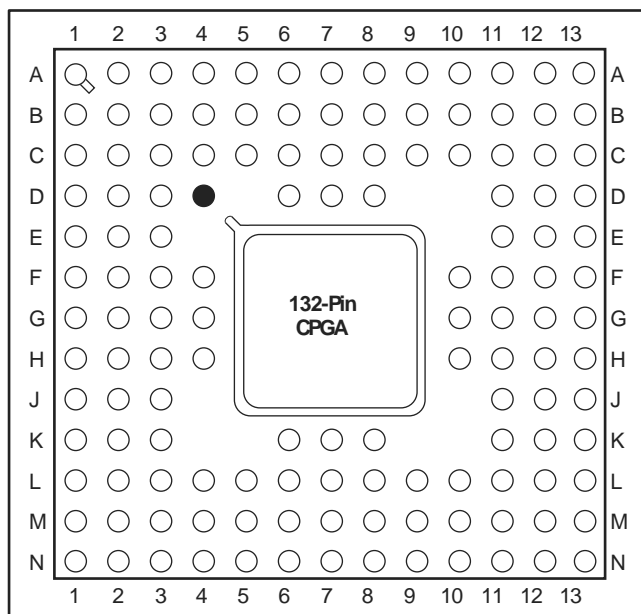
VQ100	
Pin Number	A1225A Function
2	MODE
7	GND
14	VCC
15	VCC
20	GND
32	GND
38	VCC
44	GND
50	SDO
55	GND
62	GND
63	VCC

VQ100	
Pin Number	A1225A Function
64	VCC
65	VCC
70	GND
77	SDI, I/O
82	GND
85	PRA, I/O
87	CLKA, I/O
88	VCC
90	CLKB, I/O
92	PRB, I/O
94	GND
100	DCLK, I/O

*Notes:*

1. All unlisted pin numbers are user I/Os.
2. MODE pin should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

## PG132



● Orientation Pin

### Note

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## Datasheet Categories

### **Categories**

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

#### **Product Brief**

The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

#### **Advance**

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

#### **Preliminary**

The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

#### **Production**

This version contains information that is considered to be final.

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